

### Description

The DMN2058U uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

 $V_{DS} = 20V I_D = 6.0A$  $R_{DS(ON)} < 27m\Omega W_{GS} = 4.5V$ 

## Application

Battery protection Load switch Uninterruptible power supply

### Package Marking and Ordering Information

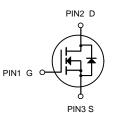
Product ID	Pack	Brand	Qty(PCS)
DMN2058U	SOT-23	HXY MOSFET	3000

## Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Symbol	Parameter	Limit	Unit	
Vds	Drain-Source Voltage	20	V	
Vgs	Gate-Source Voltage	±12	V	
ID	Drain Current-Continuous	6	А	
Ідм	Drain Current-Pulsed (Note 1)	25	А	
PD	Maximum Power Dissipation	0.35	W	
Tj,Tstg	Operating Junction and Storage Temperature Range -55 To		°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	100	°C/W	







N-Channel MOSFET



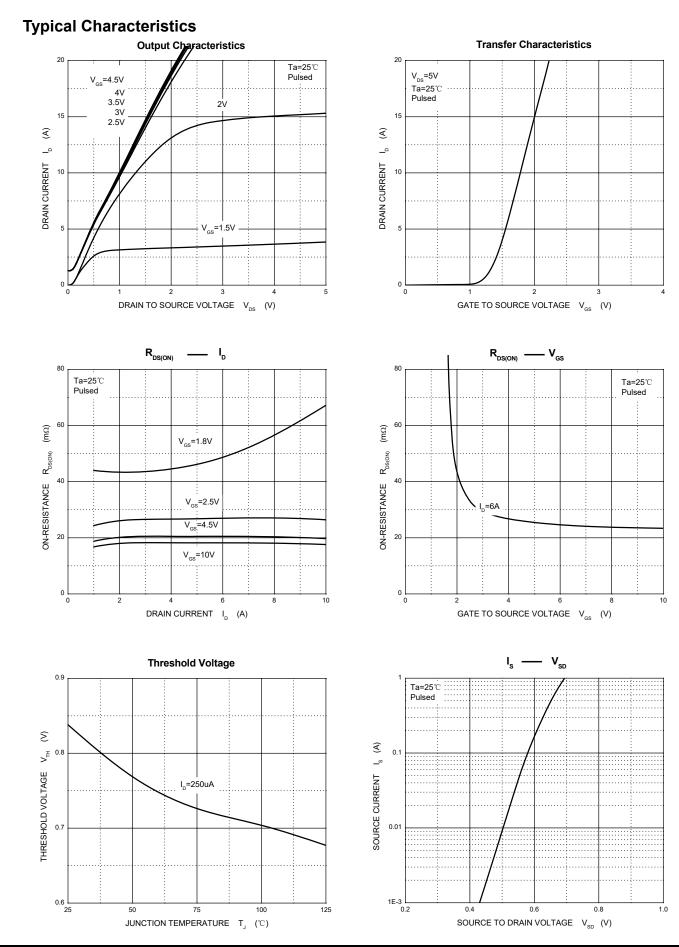
## **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit	
STATIC PARAMETERS							
Drain-source breakdown voltage	V (BR) DSS	Vgs = 0V, Id =250µA	20			V	
Gate-source leakage current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±12V			±100	nA	
Zero gate voltage drain current	I <sub>DSS</sub>	VDS =16V, VGS =0V			1.0	μA	
Gate threshold voltage	VGS(th)	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250µA	0.5	0.7	1.0	V	
Drain-source on-state resistance	Deve	Vgs =4.5V, Id =5.0A		22	27		
	RDS(on)	Vgs =2.5V, ID =4.0A		35	42	mΩ	
		Vgs =1.8V, Id =2.0A			73		
Diode forward voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =1A		0.75	1	V	
Forward transconductance	<b>g</b> <sub>fS</sub>	VDS =5V, ID =3.8A	4			S	
DYNAMIC PARAMETERS*							
Input capacitance	C <sub>iss</sub>			630		pF	
Output capacitance	C <sub>oss</sub>	Vps =10V,Vgs =0V,f =1MHz		164			
Reverse transfer capacitance	C <sub>rss</sub>			137			
Gate resistance	Rg	VDS =0V,VGS =0V,f =1MHz		1.5		Ω	
SWITCHING PARAMETERS*							
Turn-on delay time	td(on)			5.5			
Rise time	tr	$V_{GS}$ =5V, $V_{DS}$ =10V,		14		no	
Turn-off delay time	td(off)	$R_L=1.7\Omega, R_{GEN}=6\Omega$		29		ns	
Fall time	tr	]		10.2			

\*These parameters have no way to verify.



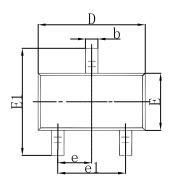
# DMN2058U N-Channel Enhancement Mode MOSFET

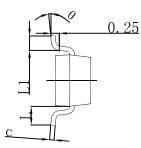


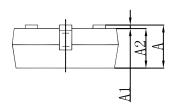
Shenzhen HuaXuanYang Electronics CO.,LTD



# **SOT-23 Package Outline Dimensions**

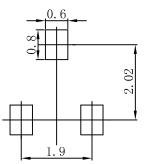






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# SOT-23 Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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